

# 3.3 - 3.7 GHz 1W MMIC

#### **FEATURES**

• P-1 dB: 30 dBm

• Small Signal Gain: 30 dB

• Power Added Efficiency: 25 %

• IP3: 39 dBm

• Match to 50  $\Omega$  operation

• Bias condition: 650 mA @ 7 V

#### PHOTO ENLARGEMENT



#### **DESCRIPTION**

The TC3331 is a 2-stage PHEMT MMIC power amplifier. It is designed for use in low cost and high volume 3.3-3.7 GHz band applications. The MMIC is matched to  $50\Omega$  operation. It provides a typical gain of 30 dB and P1dB power of 30 dBm. Typical bias condition is 7V at 650 mA. The MMIC is packaged in a copper based ceramic 10 pins power package. The copper based carrier of the package allows direct soldering of the device to the PCB.

#### **APPLICATIONS**

- Wireless Internet Access
- Wireless Local Loop
- Two way radio

## **ELECTRICAL SPECIFICATIONS (Ta = 25 °C)**

SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNITS
FREQ	Frequency Range	3.3		3.7	GHz
SSG	SSG Small Signal Gain		30		dB
GOF	Small Signal Gain Flatness		±0.5		
P <sub>-1</sub> dB	Output Power at 1 dB Gain Compression	29	30		dBm
P <sub>-3</sub> dB	Output Power at 3 dB Gain Compression	30	31		dBm
IP3	Third Order Intercept Point	37	39		dBm
VSWR, IN	Input VSWR		2:1		
VDD	Supply Voltage		7		Volt
Vg	Gate Voltage	-0.6	-1.0	-1.5	Volt
IDD	Current Supply Without RF		650		mA
IDP <sub>-1</sub>	Current Supply @ Pout=P <sub>-1</sub> dB		670		mA
ηα	Power Added Efficiency		25		%



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# **Absolute Maximum Ratings**

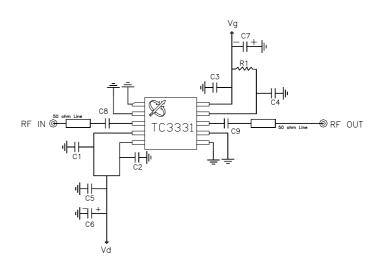
Symbol	Parameter/Conditions	Min.	Max.	Units
$V_{dd}$	Drain-Source Voltage		12	Volts
$I_{dd}$	Total Drain Current		2200	mA
Pin	RF Input Power		7	dBm
P <sub>t</sub>	Power Dissipation		9	W
T <sub>ch</sub>	Operating Channel Temperature		175	°C
$T_{STG}$	Storage Temperature	-65	175	°C

## Note:

- 1. This GaAs MMIC is susceptible to damage from Electrostatic Discharge. Proper precautions should be used when handling these devices.
- 2. Specifications subject to change without notice.

#### **TEST CIRCUITS**

**Evaluation Board Schematic** 



## **EVALUATION BOARD**

**PCB Material: RO4003** 

ER = 3.38

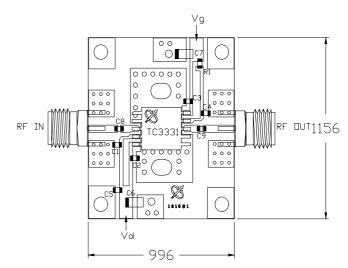
Thickness = 20 mil

Unit: mil

 DXF file of the PCB can be downloaded from our web-site

at www.transcominc.com.tw

Application Notes:
For better heat sinking and grounding, it's recommended to have the via holes beneath TC3331 filled with solder and have two screws installed on required heat sink plate besides TC3331 on the PCB area.



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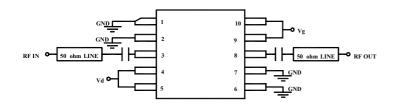
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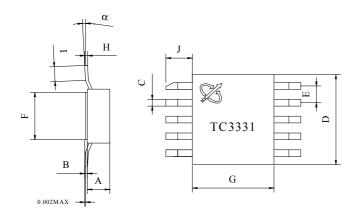
# **Evaluation Board Parts List**

Part Type	Reference Designator	Description	Manufacturer	Part Number
Capacitor	C1, C2, C3, C4	1000pF 0603	Murata	GRM39C0G102J50V
Capacitor	C6, C7	0.1 uF 0603	Murata	GRM39Y5V104Z25V
Capacitor	C5	4.7uF Tantalum Cap.		
Capacitor	C8	2.5pF 0603	Murata	GRM39C0G2R5C50V
Capacitor	C9	1.8pF 0603	Murata	GRM39C0G1R8C50V
Resistor	R1	200 ohm 0603		



Pin#	Name	Description
1, 2, 6, 7	GND	Ground
3	RF IN	RF input (internally DC blocked)
4, 5	$V_d$	MMIC drain bias
9, 10	Vg	MMIC gate bias
8	RF OUT	RF output (internally DC blocked)

# **CONNECTION DIAGRAM AND PIN DESCRIPTIONS PHYSICAL DIMENSIONS** (Unit: inch)



DIMENSION	MINIMUM	NOMINAL	MAXIMUM
A	0.054	0.057	0.060
В	0.007	0.008	0.009
С	0.017	0.020	0.023
D	0.267	0.270	0.273
Е	0.047	0.050	0.053
F	0.247	0.250	0.253
G	0.267	0.270	0.273
Н	0.007	0.008	0.009
I	0.020		0.040
J	0.073	0.080	0.087
α	0°		7°